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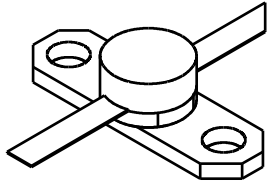
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**MS2553C**  
**35 Watts, 50 Volts**  
**Pulsed Avionics 1025 to 1150 MHz**

<p><b>GENERAL DESCRIPTION</b></p> <p>The MS2553C is a medium power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 1025-1150 MHz. The device has gold thin-film metallization and diffused ballasting for proven highest MTTF. The transistor includes input prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.</p>	<p><b>CASE OUTLINE</b>  <b>M220</b>  <b>(Common Base)</b></p> 
<p><b>ABSOLUTE MAXIMUM RATINGS</b></p> <p><b>Power Dissipation</b>  Device Dissipation @25°C (P<sub>d</sub>)      175 W (At rated pulse condition)</p> <p><b>Voltage and Current</b>  Collector to Base Voltage (BV<sub>ces</sub>)      65 V  Emitter to Base Voltage (BV<sub>ebo</sub>)      3.5 V  Collector Current (I<sub>c</sub>)      4.0 A</p> <p><b>Temperatures</b>  Storage Temperature      -65 to +150 °C  Operating Junction Temperature      +200 °C</p>	

**ELECTRICAL CHARACTERISTICS @ 25°C**

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
BV <sub>EBO</sub>	Emitter - Base Breakdown	I <sub>e</sub> = 10mA	3.5			V
BV <sub>CBO</sub>	Collector - Base Breakdown	I <sub>c</sub> = 20mA	65			V
BV <sub>CEO</sub>	Collector - Emitter Breakdown	I <sub>c</sub> = 20mA	25			V
h <sub>FE</sub>	DC – Current Gain	I <sub>c</sub> = 500mA, V <sub>ce</sub> = 5V	20			-
θ <sub>jc</sub> <sup>1,2</sup>	Thermal Resistance				0.5	°C/W

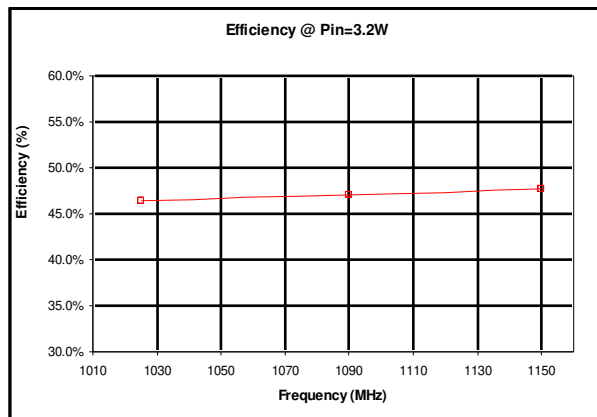
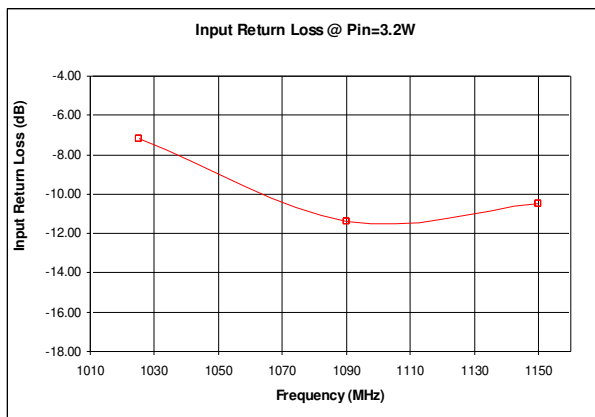
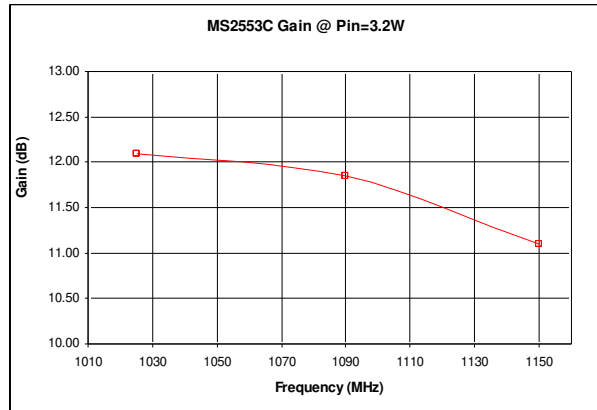
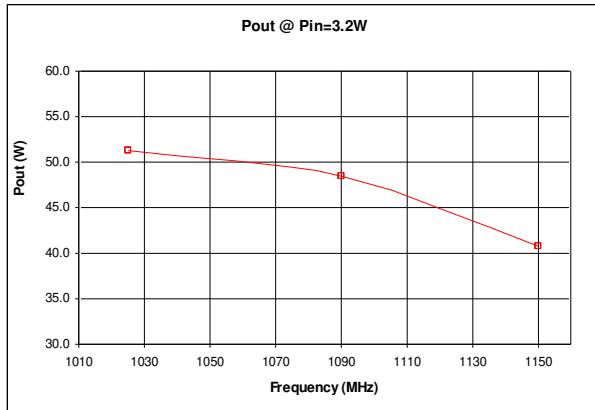
**FUNCTIONAL CHARACTERISTICS @ 25°C, V<sub>cc</sub> = 50V**

P <sub>OUT</sub>	Power Out	F = 1025/1090/1150 MHz, PW = 10μsec, DF = 1%, P <sub>IN</sub> = 3.2W	35			W
P <sub>IN</sub>	Power Input				3.2	W
G <sub>p</sub>	Power Gain		10.5			dB
η <sub>C</sub>	Collector Efficiency		40			%
P <sub>d</sub>	Pulse Droop				1	dB
?	Load Mismatch				10:1	-

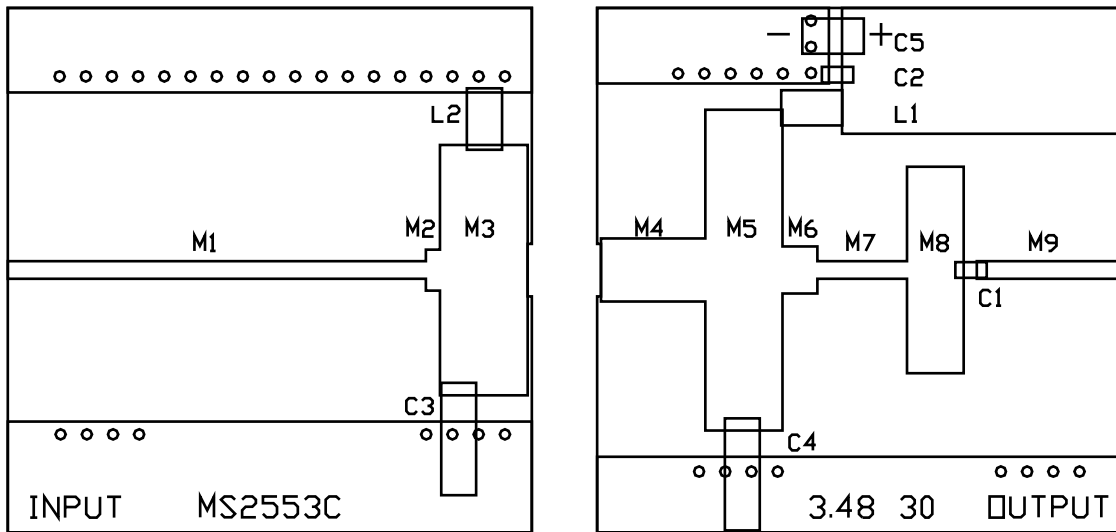
NOTES: 1. At rated output power and pulse conditions  
2. Pulse Format: PW=10μs, DF=1%

Rev. A – May. 2008

**Typical Performance (1025MHz ~ 1150MHz)**



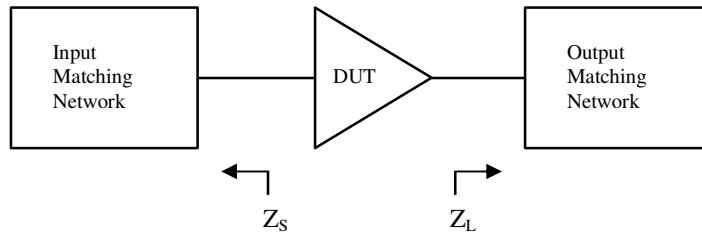
MS2553C Test Circuit Layout



MS2553C Test Circuit Component Designations and Values

Part	Description	Part	Description
C1, C2	100pF Chip Capacitor (ATC 100B)	C3, C4	.35-3.5pF Johanson Capacitor, JMC5801
C5	220uF 63V Electrolytic Capacitor	L1, L2	4 Turns, 20 AWG, IDIA 0.092"φ
M1	67 x 1596 mils (W x L)	M2	156 x 54 mils (W x L)
M3	955 x 335 mils (W x L)	M4	240 x 398 mils (W x L)
M5	1224 x 294 mils (W x L)	M6	180 x 134 mils (W x L)
M7	67 x 342 mils (W x L)	M8	788 x 216 mils (W x L)
M9	67 x 551 mils (W x L)	PCB	Rogers RO4350, $\epsilon_r=3.48$ , 30mils, 1oz

**Typical Impedance Values**

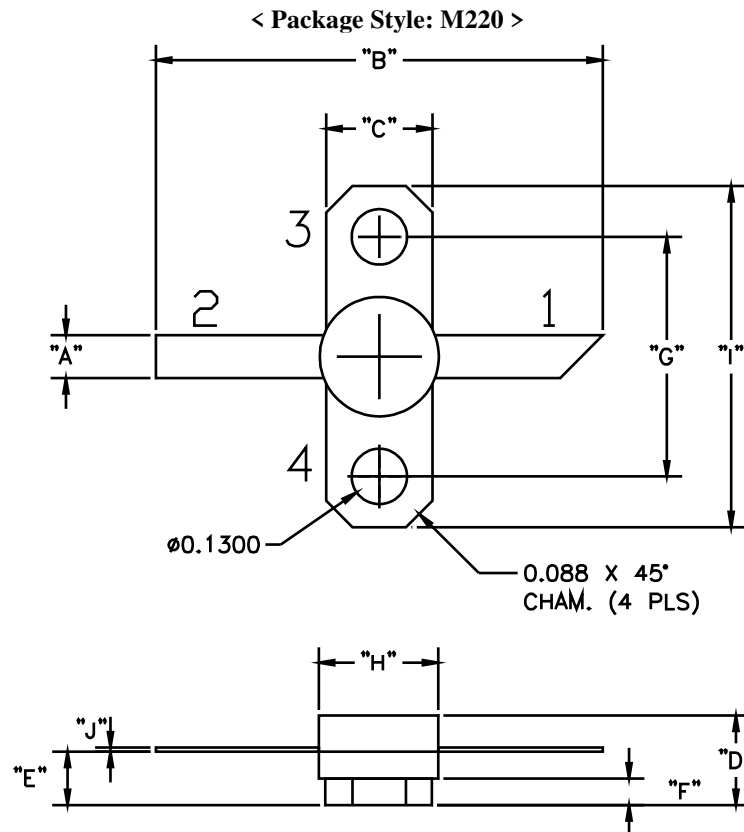


Frequency (MHz)	$Z_S$ (?S)	$Z_L$ (?S)
<b>1025</b>	<b>6.3 - j15.4</b>	<b>6.6 + j2.0</b>
<b>1090</b>	<b>5.6 - j14.5</b>	<b>7.6 + j2.6</b>
<b>1150</b>	<b>5.1 - j13.8</b>	<b>8.6 + j2.7</b>

\*  $V_{CC} = 50V$ ,  $P_{IN} = 3.2W$

\* Pulse Format: 10 $\mu$ s, 1% Long Term Duty Factor



**Package Mechanical Data**


DIMENSION					
	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.100 / 2.54		B	1.050 / 26.67	-
C	.250 / 6.35		D	-	.210 / 5.33
E	.120 / 3.05	.130 / 3.30	F	.062 / 1.58	
G	.562 / 14.28		H	-	.285 / 7.24
I	.800 / 20.32		J	.003 / 0.08	.006 / 0.15
PIN CONNECTION					
1	COLLECTOR		2	EMITTER	
3	BASE		4	BASE	